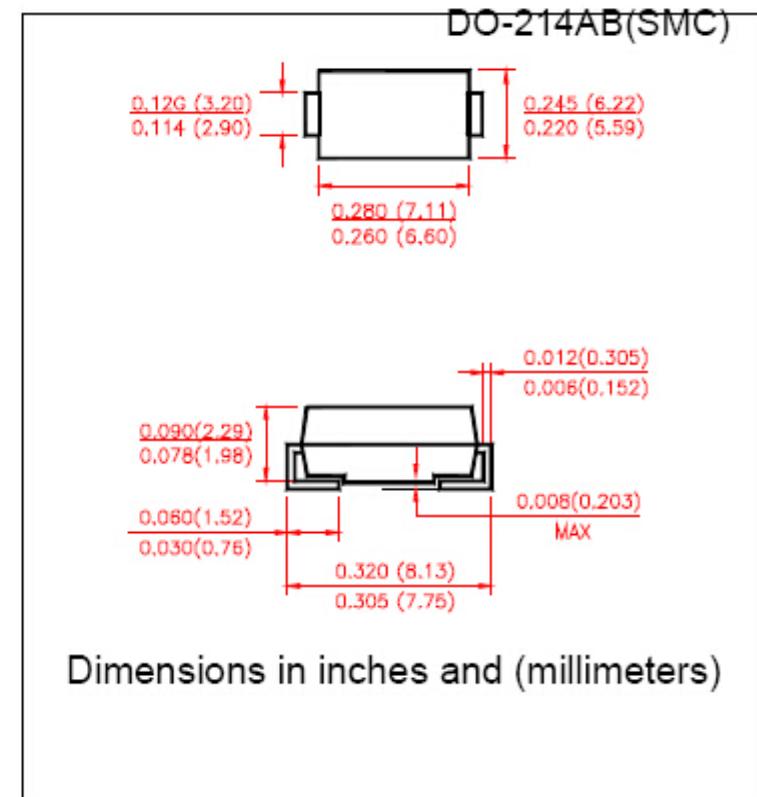


FEATURES

- Low profile surface mount package
- Built-in strain relief
- High switching speed
- Low voltage drop, high efficiency
- For use in low voltage high frequency inverters, Free wheeling, and polarity protection applications
- Guarding for over voltage protection

MECHANICAL DATA

- Case: Transfer molded plastic
- Epoxy: UL 94V-0 rate flame retardant
- Lead: Solder plated, solderable per MIL-STD-750 method 2026
- Polarity: Color band denotes cathode end
- Weight: 0.007 ounce, 0.25 gram



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

- Ratings at 25 °C ambient temperature unless otherwise specified.
- Single phase, half wave, 60Hz, resistive or inductive load.
- For capacitive load derate current by 20%.

	SYMBOLS	SS32	SS33	SS34	SS35	SS36	SS38	SS39	SS310	UNIT
Maximum Repetitive Peak Reverse Voltage	V _{RRM}	20	30	40	50	60	80	90	100	Volts
Maximum RMS Voltage	V _{RMS}	14	21	28	35	42	56	63	70	Volts
Maximum DC Blocking Voltage	V _{DC}	20	30	40	50	60	80	90	100	Volts

Maximum DC Blocking Voltage	V _{DC}	20	30	40	50	60	80	90	100	Volts
Maximum Average Forward Rectified Current at T _L see figure 1 T _L =105 °C	I _(AV)					3.0				Amps
Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load (JEDEC method)	I _{FSM}					80				Amps
Maximum Instantaneous Forward Voltage @ 3.0A(Note1)	V _F		0.55		0.75		0.85			Volts
Maximum DC Reverse Current at rated DC Blocking Voltage per element	T _A = 25 °C	I _R			0.5					mA
	T _A = 100 °C			20.0			10.0			
Typical Thermal Resistance (Note 2)	R _{θJA}				55					°C/W
	R _{θJL}				12					
Operating Junction Temperature	T _J		(-55 to +150)			(-55 to +150)				°C
Storage Temperature Range	T _{STG}				(-55 to +150)					°C

Notes:

1. Pulse test: 300 μ s pulse width, 1% duty cycle
2. PCB mounted with 0.55"×0.55"(14mm×14mm) copper pads